## NSN 5961-01-123-2433

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**Inclosure Material:** Metal **Overall Length:** 1.253 inches **Function For Which Designed:** Voltage regulator **End Application:** Hull obrp 03950 **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.423 inches and 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 82.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current horsepower metric and 115.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud

Shelf Life:

**Specification Data:** 

81349-mil-s-19500/124 government specification

N/a

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